

# Extrinsic and Intrinsic Nonlinear Hall Effects across Berry-Dipole Transitions

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Three-dimensional Hopf insulators are a class of topological phases beyond the tenfold-way classification. The critical point separating two rotation-invariant Hopf insulator phases with distinct Hopf invariants is quite different from the usual Dirac-type or Weyl-type critical points and uniquely characterized by a quantized Berry dipole. Close to such Berry-dipole transitions, we find that the extrinsic and intrinsic nonlinear Hall conductivity tensors in the weakly doped regime are characterized by two universal functions of the ratio between doping level and bulk energy gap, and are directly proportional to the change in Hopf invariant across the transition. Our work suggests that the nonlinear Hall effects display a general-sense quantized behavior across Berry-dipole transitions, establishing a correspondence between nonlinear Hall effects and Hopf invariant.

Quantum responses that can extract topological invariant information are of great interest in condensed matter physics. For topological insulating systems, since the topological protection and the existence of a bulk energy gap can tolerate perturbations, there may exist quantum responses that are quantized and directly connected to the topological invariant encoded in the band structure [1], with the quantum (anomalous) Hall insulators being the most well-known example where the Hall conductance is quantized and connected to the Chern number [2–4]. In comparison, metallic systems are known to hardly support quantized responses since the Fermi surface deforms under perturbations and generally lacks of a topological characterization. Known exceptions include ballistic conductors where the conductance is shown to be quantized and connected to the Euler characteristic of the Fermi sea [5, 6], and Weyl semimetals without inversion and mirror symmetries where a quantized circular photogalvanic effect can emerge in the absence of disorder and interactions [7, 8]. It is worth mentioning that the circular photogalvanic effect is a second-order optical response effect and its quantization in Weyl semimetals is rooted in the quantized Berry-monopole charge of the Weyl point enclosed by the Fermi surface [9].

Recently, extrinsic nonlinear Hall effect (ENHE) and intrinsic nonlinear Hall effect (INHE) in metallic systems, as another two kinds of second-order quantum responses derived by semiclassical equations of motion, have gained considerable interest since they have a quantum geometry origin and can emerge in systems without linear-order anomalous Hall effect [10–12]. It was shown that the ENHE and INHE depend on the Berry dipole [13] and Berry-connection polarizability (BCP) [14], respectively, and both of them are Fermi-surface properties. The adjectives “extrinsic” and “intrinsic” applied to distinguish them reflect one essential difference between these two kinds of nonlinear Hall effects, namely, the former depends linearly on the relaxation time associated with carrier scatterings [13], whereas the latter does not involve any time scale and only depends on the band geometry quantity [14]. Although both of them require the breaking of inversion symmetry, the ENHE is a time-reversal-even effect and can emerge in systems with time-reversal symmetry, but the INHE is a time-reversal-odd effect and can only appear in sys-

tems without time-reversal symmetry. Interestingly, when the system has neither time-reversal symmetry nor inversion symmetry, but their combination, the  $PT$  symmetry, the ENHE is absent as the Berry curvature is forced to vanish [15], whereas the INHE can be significant. Two recent works have shown that the INHE could be applied to measure the Néel vector of  $PT$ -symmetric antiferromagnets [16, 17].

Since various quantum geometry quantities are prominent near band crossings or avoid crossings, topological semimetals or doped small-gap topological insulators are ideal material systems to seek for strong ENHE and INHE [18–36]. For topological insulators, it is known that the change of global topology across a topological phase transition is a result of the dramatic change in quantum geometry near the band edge. Thus, although the ENHE and INHE are Fermi-surface properties that are generally not possible to determine the topological invariant associated with the whole Brillouin zone, they are possible to detect the change of band topology if the topological insulators are weakly doped. Previous works indeed found that the ENHE can manifest topological phase transitions described by low-energy Dirac Hamiltonians through the dramatic sign change of nonlinear Hall conductivity tensor (NHCT) [22, 37, 38]. However, since therein the tilt or warping of massive Dirac cone is necessary to have nonzero ENHE [13, 26], the NHCT does not have a simple and universal form revealing the change of topological invariant.

In this work, we explore the behaviors of ENHE and INHE across the critical regime of three-dimensional rotation-invariant Hopf insulators. As a class of topological insulators beyond the tenfold-way classification [39, 40], the Hopf insulators follow a  $Z$  classification and do not have time-reversal and inversion symmetries [41–45]. In addition, the critical points separating two rotation-invariant Hopf insulator phases with distinct Hopf invariants is characterized by a quantized Berry dipole [46], which is quite different from the usual Dirac-type or Weyl-type critical point characterized by a  $Z_2$  or Berry-monopole charge [47]. Because of the unique property of the critical point, we find that close to the transition, the extrinsic and intrinsic NHCTs in the weakly doped regime are characterized by two universal functions and explicitly contain the information of the change in Hopf invariant across

the transition. Although extrinsic and intrinsic NHCTs are independent quantities of different origins, here they display similar laws and are simply related across the critical regime.

*Rotation-invariant Hopf insulators and Berry-dipole transitions.*— Hopf insulators have a diversity of model realizations [41–43, 48, 49]. In this work we focus on the two-band realization for simplicity. The minimal models for Hopf insulators are constructed by the so-called Hopf map [41]

$$\mathcal{H}(\mathbf{k}) = \mathbf{d}(\mathbf{k}) \cdot \boldsymbol{\sigma} \quad (1)$$

with the three components of the  $\mathbf{d}$ -vector given by

$$\begin{aligned} d_i(\mathbf{k}) &= \zeta^\dagger(\mathbf{k}) \sigma_i \zeta(\mathbf{k}), \zeta(\mathbf{k}) = (\zeta_1(\mathbf{k}), \zeta_2(\mathbf{k}))^T, \\ \zeta_1(\mathbf{k}) &= \eta_1(\mathbf{k}) + i\eta_2(\mathbf{k}), \zeta_2(\mathbf{k}) = \eta_3(\mathbf{k}) + i\eta_4(\mathbf{k}), \end{aligned} \quad (2)$$

where  $\sigma_i$  are the Pauli matrices, and  $\eta_i(\mathbf{k})$  are real functions of momentum. Mathematically, the above equations define a map from  $S^3$  to  $S^2$ . In this paper, we focus on models with rotation symmetry about the  $z$  axis. To be specific, we consider [46]

$$\begin{aligned} \zeta_1(\mathbf{k}) &= \lambda^n [\sin(k_x a) + i \sin(k_y a)]^n, \\ \zeta_2(\mathbf{k}) &= \lambda_z \sin(k_z c) + i[M + t \sum_{i=x,y,z} \cos(k_i a_i)], \end{aligned} \quad (3)$$

where the lattice constants  $a_x = a_y = a$  and  $a_z = c$ . The energy spectra of the Hamiltonian take the simple form

$$E_{\pm}(\mathbf{k}) = \pm(|\zeta_1(\mathbf{k})|^2 + |\zeta_2(\mathbf{k})|^2). \quad (4)$$

Obviously, the energy gap can only close at time-reversal invariant momenta of the Brillouin zone. Without loss of generality, we consider that the band edge is located at  $\Gamma = (0, 0, 0)$ , then an expansion of the complex spinor up to the leading order in momentum gives

$$\begin{aligned} \zeta_1(\mathbf{k}) &= v^n (k_x + ik_y)^n, \\ \zeta_2(\mathbf{k}) &= v_z k_z + im, \end{aligned} \quad (5)$$

where  $v = \lambda a$ ,  $v_z = \lambda_z c$  and  $m = M + 3t$ . Accordingly, the low-energy Hopf Hamiltonian has the form

$$\begin{aligned} \mathcal{H}(\mathbf{k}) &= 2v^n k_\rho^n (v_z k_z \cos n\theta + m \sin n\theta) \sigma_x \\ &\quad + 2v^n k_\rho^n (m \cos n\theta - v_z k_z \sin n\theta) \sigma_y \\ &\quad + (v^{2n} k_\rho^{2n} - v_z^2 k_z^2 - m^2) \sigma_z, \end{aligned} \quad (6)$$

where  $k_\rho = \sqrt{k_x^2 + k_y^2}$ , and  $\theta$  is the polar angle in the  $k_x$ - $k_y$  plane. The low-energy spectra are given by

$$E_{\pm}(\mathbf{k}) = \pm(v^{2n} k_\rho^{2n} + v_z^2 k_z^2 + m^2). \quad (7)$$

For the simplest case  $n = 1$ , one sees that the low-energy Hamiltonian at the critical point  $m = 0$  is distinct to the Weyl Hamiltonian and the energy dispersion is quadratic rather than the linear dispersion of usual critical points.

For the Hamiltonian constructed by Hopf map, the Hopf invariant characterizing it can be determined by [43]

$$N_h = \frac{1}{2\pi^2} \int d^3k \epsilon_{abcd} \hat{\eta}_a \partial_{k_x} \hat{\eta}_b \partial_{k_y} \hat{\eta}_c \partial_{k_z} \hat{\eta}_d, \quad (8)$$

where  $\hat{\eta}_i = \eta_i / \sqrt{\eta_1^2 + \eta_2^2 + \eta_3^2 + \eta_4^2}$ ,  $\epsilon_{abcd}$  is the fourth-order antisymmetric tensor, and a sum over repeated indices is implied. For the low-energy Hopf Hamiltonian, one has [50]

$$N_h = -\text{sgn}(v_z m) \frac{n}{2}. \quad (9)$$

When  $m$  changes sign, the Hopf invariant changes by  $n$ . It is worth emphasizing that the low-energy Hopf Hamiltonian can only determine the change of Hopf invariant since it only faithfully captures the low-energy part of physics. One needs the tight-binding Hamiltonian to determine the absolute values of Hopf invariant before and after the transition.

For the low-energy Hopf Hamiltonian (6), the three components of the Berry curvature can be determined by [51]

$$\Omega_i^{(\pm)}(\mathbf{k}) = \pm \epsilon_{ijl} \frac{\mathbf{d}(\mathbf{k}) \cdot (\partial_{k_i} \mathbf{d}(\mathbf{k}) \times \partial_{k_j} \mathbf{d}(\mathbf{k}))}{4d^3(\mathbf{k})}, \quad (10)$$

where  $d(\mathbf{k}) = |\mathbf{d}(\mathbf{k})|$  is the norm of the  $\mathbf{d}$ -vector, the superscript  $+$  ( $-$ ) refers to the conduction (valence) band, and  $\epsilon_{ijl}$  is the third-order antisymmetric tensor. An explicit calculation gives [50]

$$\begin{aligned} \Omega_x^{(\pm)}(\mathbf{k}) &= \pm \frac{2nv_z v^{2n} k_\rho^{2n-1} (m \sin \theta + v_z k_z \cos \theta)}{d^2(\mathbf{k})}, \\ \Omega_y^{(\pm)}(\mathbf{k}) &= \pm \frac{2nv_z v^{2n} k_\rho^{2n-1} (-m \cos \theta + v_z k_z \sin \theta)}{d^2(\mathbf{k})}, \\ \Omega_z^{(\pm)}(\mathbf{k}) &= \pm \frac{2n^2 v^{2n} k_\rho^{2(n-1)} (m^2 + v_z^2 k_z^2)}{d^2(\mathbf{k})}. \end{aligned} \quad (11)$$

At the critical point  $m = 0$ , it turns out that the integral of the Berry curvature over a closed surface in momentum space identically vanishes, however, the integral over the upper ( $k_z > 0$ ) or lower ( $k_z < 0$ ) half of the surface is quantized, namely [46],

$$\frac{1}{2\pi} \int_{k_z > 0} \boldsymbol{\Omega} \cdot d\mathbf{S} = n. \quad (12)$$

This unique property again reveals that the critical point between two distinct Hopf insulator phases is distinct to the Weyl point characterized by a Berry monopole [9]. Pictorially, the Berry-flux distribution associated with the critical point resembles a dipole with the Berry monopole and antimonopole forming the dipole infinitely close and mirror-symmetric about the  $k_z = 0$  plane [46, 52]. The results in Eqs.9 and (12) indicate that the change of Hopf invariant across the transition is equal to the quantized value of the Berry dipole at the critical point, similar to that the change of Chern number in a two-dimensional system is equal to the Berry-monopole charge it crosses [9].

Since the critical point of rotation-invariant Hopf insulators is characterized by a quantized Berry dipole and the ENHE is related to the Berry dipole, it is natural to expect that the ENHE would display some novel behaviors across such Berry-dipole transitions.

*ENHE across Berry-dipole transitions.*— Sodemann and Fu revealed that an ac electric field would result in a mixture of dc

and second-harmonic Hall-type currents in the second-order-response regime in systems without inversion symmetry[13], i.e.,  $\mathbf{j} = \mathbf{j}^0 + \mathbf{j}^{2\omega}$  with  $j_i^0 = \chi_{ijk}\mathcal{E}_j\mathcal{E}_k^*$  and  $j_i^{2\omega} = \chi_{ijk}\mathcal{E}_j\mathcal{E}_k$ . The extrinsic NHCT is given by[13]

$$\chi_{ijk}^{\text{ext}} = -\frac{e^3\tau}{2(1+i\omega\tau)}\epsilon_{ilk}D_{jl}, \quad (13)$$

where  $\tau$  denotes the relaxation time whose value depends on the carrier scattering.  $D_{jl}$  is the Berry dipole given by [13]

$$D_{jl} = -\sum_{\alpha} \int \frac{d^3k}{(2\pi)^3} \partial_{k_j} f^{(\alpha)}(\mathbf{k}) \Omega_l^{(\alpha)}(\mathbf{k}), \quad (14)$$

where the sum is over all bands. The derivative of the Fermi-Dirac distribution function,  $\partial_{k_j} f^{(\alpha)}$ , is equal to  $-\partial_{k_j} E_{\alpha} \delta(\mu - E_{\alpha})$  at the zero-temperature limit, indicating that the Berry dipole  $D_{jl}$  is a Fermi-surface property.

Using the Berry curvature in Eq.(11), we find that the extrinsic NHCT only contains four nonzero components, including  $\chi_{zxx}^{\text{ext}}, \chi_{xxz}^{\text{ext}}, \chi_{zyy}^{\text{ext}}, \chi_{yyz}^{\text{ext}}$ . However, there is in fact only one independent component. This can be inferred by noting that the rotation symmetry forces  $\chi_{zxx}^{\text{ext}} = \chi_{zyy}^{\text{ext}}$ , and the Hall nature forces  $\chi_{zxx}^{\text{ext}} = -\chi_{xxz}^{\text{ext}}$  and  $\chi_{zyy}^{\text{ext}} = -\chi_{yyz}^{\text{ext}}$ , which can also be simply inferred from the antisymmetric property of the Levi-Civita symbol in Eq.(13). Focusing on the zero-temperature limit and only showing the explicit form of  $\chi_{zxx}^{\text{ext}}$ , one has [50]

$$\chi_{zxx}^{\text{ext}} = N_h \chi_1 \mathcal{B}_1(\mu/m^2), \quad (15)$$

where  $N_h$  is the Hopf invariant given by Eq.(9),  $\chi_1 = e^3\tau/2(1+i\omega\tau)$ , and  $\mathcal{B}_1(x)$  is a dimensionless universal function of the form

$$\mathcal{B}_1(x) = \frac{2(x-1)^{3/2}}{3\pi^2 x^2} \Theta(x-1). \quad (16)$$

Here electronic doping is assumed, i.e.,  $\mu > 0$ . Since the energy gap of the low-energy Hamiltonian (6) is equal to  $2m^2$ ,  $\mathcal{B}_1(\mu/m^2)$  is a universal function of the ratio between chemical potential and bulk energy gap.

According to Eqs.(9) and (15), one sees that the extrinsic NHCT reverses its sign across a Berry-dipole transition, thus allowing a sensitive probe of the transition. Remarkably, if the relaxation time is assumed to be constant, the extrinsic NHCT turns out to be a universal function multiplied with the change of Hopf invariant across the transition. To the best of our knowledge, this is the thus-far-only-known system that the ENHE displays a general-sense quantized behavior with a correspondence to topological invariant. Using this result, it is possible to precisely probe the change in topological invariant across Berry-dipole transitions by measuring the evolution of current with the change of doping level.

*INHE across Berry-dipole transitions.*— Since the time-reversal and inversion symmetries are both broken in the Hopf Hamiltonian, the INHE is also allowed. However, quite different from the ENHE, the INHE introduced by Gao, Yang and Niu depends on a band geometry quantity known as BCP [14],

which does not have a direct connection with the Berry curvature. Although the ENHE and INHE have different origins, as we will show below, a simple relation exists between the Berry curvature and the BCP for the low-energy Hopf Hamiltonian, leading to that the INHE displays a similar behavior like the ENHE across Berry-dipole transitions.

The Hall current originating from INHE has the form  $j_{\alpha}^{\text{int}} = \chi_{\alpha\beta\gamma}^{\text{int}} \mathcal{E}_{\beta} \mathcal{E}_{\gamma}$ , where the intrinsic NHCT is given by [14, 16, 17]

$$\chi_{\alpha\beta\gamma}^{\text{int}} = -e^3 \sum_n \int \frac{d^3k}{(2\pi)^3} v_{\alpha}^{(n)} G_{\beta\gamma}^{(n)} \frac{\partial f(E_n)}{\partial E_n} - (\alpha \leftrightarrow \beta), \quad (17)$$

where  $E_n, v_{\alpha}^{(n)} = \partial E_n / \partial k_{\alpha}$  and  $G_{\beta\gamma}^{(n)}$  denote the  $n$ th band's dispersion, velocity in the  $\alpha$  direction and BCP, respectively. Their  $\mathbf{k}$ -dependence are made implicit in Eq.(17). The gauge-independent BCP is given by [14, 16, 17]

$$G_{\beta\gamma}^{(n)}(\mathbf{k}) = 2\text{Re} \sum_{m \neq n} \frac{A_{nm,\beta}(\mathbf{k}) A_{mn,\gamma}(\mathbf{k})}{E_n(\mathbf{k}) - E_m(\mathbf{k})}, \quad (18)$$

where  $A_{nm,\beta}(\mathbf{k}) = i \langle u_n(\mathbf{k}) | \partial_{k_{\beta}} u_m(\mathbf{k}) \rangle$  is the interband Berry connection. From Eq.(17), it is apparent that  $\chi_{\alpha\beta\gamma}^{\text{int}} = -\chi_{\beta\alpha\gamma}^{\text{int}}$ .

For the two-band Hamiltonian considered, one has [14]

$$G_{\beta\gamma}^{(+)}(\mathbf{k}) = -\frac{\partial_{k_{\beta}} \hat{\mathbf{d}}(\mathbf{k}) \cdot \partial_{k_{\gamma}} \hat{\mathbf{d}}(\mathbf{k})}{4d(\mathbf{k})} = -G_{\beta\gamma}^{(-)}(\mathbf{k}), \quad (19)$$

where  $\hat{\mathbf{d}}(\mathbf{k}) = \mathbf{d}(\mathbf{k})/d(\mathbf{k})$  is the normalized  $\mathbf{d}$ -vector. Interestingly, the numerator in Eq.(19) suggests that the BCP is related to the quantum metric for a two-band Hamiltonian. Since the BCP is a symmetric tensor, i.e.,  $G_{\beta\gamma}^{(\pm)}(\mathbf{k}) = G_{\gamma\beta}^{(\pm)}(\mathbf{k})$ , there are six independent components. By straightforward calculations, one has [50]

$$\begin{aligned} G_{xx}^{(\pm)}(\mathbf{k}) &= G_{yy}^{(\pm)}(\mathbf{k}) = \mp \frac{n^2 v^2 k_{\rho}^{2n-2} (m^2 + v_z^2 k_z^2)}{d^3(\mathbf{k})}, \\ G_{zz}^{(\pm)}(\mathbf{k}) &= \mp \frac{v_z^2 v^2 k_{\rho}^{2n}}{d^3(\mathbf{k})}, \quad G_{xy}^{(\pm)}(\mathbf{k}) = 0, \\ G_{xz}^{(\pm)}(\mathbf{k}) &= \pm \frac{nv^2 n v_z k_{\rho}^{2n-1} (m \sin \theta + v_z k_z \cos \theta)}{d^3(\mathbf{k})}, \\ G_{yz}^{(\pm)}(\mathbf{k}) &= \pm \frac{nv^2 n v_z k_{\rho}^{2n-1} (-m \cos \theta + v_z k_z \sin \theta)}{d^3(\mathbf{k})}. \end{aligned} \quad (20)$$

A close look of Eqs.(11) and (20) finds that four of the six independent components of the BCP tensor have a simple relation with the three components of the Berry curvature, i.e.,

$$\Omega_x^{(\pm)} = 2dG_{xz}^{(\pm)}, \Omega_y^{(\pm)} = 2dG_{yz}^{(\pm)}, \Omega_z^{(\pm)} = -2dG_{xy}^{(\pm)}. \quad (21)$$

Bringing Eq.(20) into Eq.(17), one finds that  $\chi_{\alpha\beta\gamma}^{\text{int}}$  is nonzero only when  $\alpha \neq \beta \neq \gamma$ , and the nonzero independent components have the simple relation [50]

$$\chi_{xyz}^{\text{int}} = -2\chi_{yzx}^{\text{int}} = -2\chi_{zyx}^{\text{int}}. \quad (22)$$

Also focusing on the zero-temperature limit and only showing the explicit form of  $\chi_{xyz}^{\text{int}}$ , one has [50]

$$\chi_{xyz}^{\text{int}} = -N_h \chi_2 \mathcal{B}_2(\mu/m^2), \quad (23)$$

where  $\chi_2 = e^3/m^2$  and

$$\mathcal{B}_2(x) = \frac{2(x-1)^{3/2}}{3\pi^2 x^3} \Theta(x-1) = \frac{\mathcal{B}_1(x)}{x}. \quad (24)$$

Compared to the ENHE, one sees that the INHE displays a similar behavior, but a big difference is that the factor  $\chi_2$  suggests that the peak of the intrinsic NHCT goes divergent as the bulk energy gap decreases to infinitely small but nonzero (note that the critical point of the low-energy Hopf Hamiltonian has emergent inversion symmetry so the INHE is forced to vanish when  $m = 0$ ). This property implies that the INHE can provide an even more sensitive probe of the Berry-dipole transition. Furthermore, one can find  $\chi^{\text{ext}}/\chi^{\text{int}} \sim m^2\tau$ , thus a simultaneous study of ENHE and INHE can also provide a probe of the relaxation time.

*Discussions and conclusions.*— It is worth emphasizing that because the low-energy Hopf Hamiltonian does not have time-reversal symmetry, the linear Hall conductivity tensor  $\sigma_{ij}$  does not identically vanish. By analyzing the Berry curvature in Eq.(11), it is easy to find that  $\sigma_{xz}$  and  $\sigma_{yz}$  identically vanish, and only  $\sigma_{xy}$  is finite in the doped regime. This can also be figured out by noting that, despite the absence of global time-reversal symmetry, the Hamiltonian has spinless time-reversal symmetry at any  $k_y$  or  $k_x$  plane. This result suggests that the linear anomalous Hall effect only appears in the  $xy$  plane. For the ENHE and INHE, their nonzero components indicate that the Hall current will flow in the  $z$  direction if the electric vector lies in the  $xy$  plane, thus they can be easily distinguished from the linear-order Hall current according to the current direction. Of course, they can also be distinguished by using lock-in method since the linear-order and second-order Hall signals have different dependence on the frequency of the ac electric field. The ENHE and INHE can also be easily distinguished from each other by controlling the electric vector to lie in the  $xz$  or  $yz$  plane. For the former, the current will flow in parallel with the electric component in the  $xy$  plane, while the latter will flow perpendicular to the electric vector plane.

Now we discuss potential systems to observe our predictions. In theory, the two-band Hopf insulators considered provide the simplest realization of Berry-dipole transitions, however, two-band Hopf insulators remain elusive in experiments. Since the critical point associated with a quantized Berry dipole is equivalent to the overlap of two mirror-symmetry-related Weyl points [52], a potential route to realize the Berry-dipole transition is to consider magnetic Weyl semimetals with a mirror plane and then break appropriate symmetries to gap out the nodal points [46]. The experimental implementation of two-band Hopf insulators has also been explored in the context of cold-atom systems, and it was suggested that cold-atom systems with long-range dipolar interaction and

Floquet modulations may realize the long-sought Hopf insulators [53, 54]. On the other hand, a recent work revealed that Bloch oscillations provide a counterpart realization of ENHE in cold-atom systems [55]. Therefore, the cold-atom systems are a potential platform to observe our predictions. Furthermore, it is worth pointing out that Berry-dipole transitions are not restricted to two-band realizations. There also exist  $N$ -fold ( $N \geq 3$ ) Berry-dipole critical points with linear dispersion [49]. Compared to the two-band realizations of Berry-dipole transitions, an important advantage of the  $N$ -band ( $N \geq 3$ ) realizations is that their corresponding tight-binding Hamiltonians can only involve nearest-neighbor hoppings, and are thus more feasible in experiments. By investigating the  $N = 3$  case, we find that the ENHE and INHE do also display the expected general-sense quantized behaviors across the Berry-dipole transition [50]. The only different is that the associated universal functions have a different form due to the difference in dispersion. This suggests that this class of systems can also be applied to test our predictions on the ENHE and INHE across Berry-dipole transitions.

In conclusion, we have shown that the nonlinear Hall effects display a general-sense quantized behavior across Berry-dipole transitions, building up a correspondence between nonlinear Hall effects and Hopf invariant. A direction for future study is to consider semimetals with nodal points or insulators with critical points characterized by higher-order Berry moments and explore what kinds of quantum responses can uniquely reflect their existence.

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